

SCES467B-JULY 2003-REVISED APRIL 2008

SINGLE BUS BUFFER GATE WITH 3-STATE OUTPUT

FEATURES

- Qualified for Automotive Applications
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Low Power Consumption, 10-μA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

DESCRIPTION/ORDERING INFORMATION

This single bus buffer gate is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC1G126-Q1 is a single line driver with a 3-state output. The output is disabled when the output-enable (OE) input is low.

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION⁽¹⁾

| T _A | PACKAG | E ⁽²⁾ | ORDERABLE PART NUMBER | TOP-SIDE MARKING ⁽³⁾ |
|----------------|--------------------|------------------|-----------------------|---------------------------------|
| –40°C to 125°C | SOT (SOT-23) – DBV | Reel of 3000 | 1P1G126QDBVRQ1 | C26_ |

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

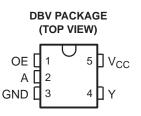
(3) DBV: The actual top-side marking has one additional character that designates the wafer fab/assembly site.

| - | | |
|------|-----|--------|
| INPU | JTS | OUTPUT |
| OE | Α | Y |
| Н | Н | Н |
| Н | L | L |
| L | Х | Z |

FUNCTION TABLE

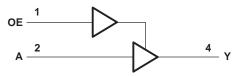


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LOGIC DIAGRAM (POSITIVE LOGIC)



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|------------------|--|--------------------|-----------------------|------|------|
| V _{CC} | Supply voltage range | | -0.5 | 6.5 | V |
| VI | Input voltage range ⁽²⁾ | -0.5 | 6.5 | V | |
| Vo | Voltage range applied to any output in the high-in | -0.5 | 6.5 | V | |
| Vo | Voltage range applied to any output in the high o | -0.5 | V _{CC} + 0.5 | V | |
| I _{IK} | Input clamp current | V ₁ < 0 | | -50 | mA |
| I _{OK} | Output clamp current | V _O < 0 | | -50 | mA |
| I _O | Continuous output current | | | ±50 | mA |
| | Continuous current through V _{CC} or GND | | | ±100 | mA |
| θ_{JA} | Package thermal impedance ⁽⁴⁾ | | 206 | °C/W | |
| T _{stg} | Storage temperature range | | -65 | 150 | °C |

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed. The value of V_{CC} is provided in the recommended operating conditions table. (2)

(3)

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

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Recommended Operating Conditions⁽¹⁾

| | | | MIN | MAX | UNIT |
|-----------------|------------------------------------|--|---------------------|----------------------|------|
| V | Supply voltogo | Operating | 1.65 | 5.5 | V |
| V _{CC} | Supply voltage | Data retention only | 1.5 | | v |
| | | V _{CC} = 1.65 V to 1.95 V | $0.65 	imes V_{CC}$ | | |
| V | Ligh lovel input veltage | V_{CC} = 2.3 V to 2.7 V | 1.7 | | V |
| V _{IH} | High-level input voltage | $V_{CC} = 3 V \text{ to } 3.6 V$ | 2 | | v |
| | | V_{CC} = 4.5 V to 5.5 V | $0.7 	imes V_{CC}$ | | |
| | | $V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$ | | $0.35 \times V_{CC}$ | |
| V | Low-level input voltage | V_{CC} = 2.3 V to 2.7 V | | 0.7 | V |
| V _{IL} | Low-level input voltage | $V_{CC} = 3 V \text{ to } 3.6 V$ | | 0.8 | v |
| | | V_{CC} = 4.5 V to 5.5 V | | $0.3 \times V_{CC}$ | |
| VI | Input voltage | | 0 | 5.5 | V |
| Vo | Output voltage | | 0 | V _{CC} | V |
| | | V _{CC} = 1.65 V | | -4 | |
| | | $V_{CC} = 2.3 V$ | | -8 | |
| I _{OH} | High-level output current | $V_{CC} = 3 V$ | | -16 | mA |
| | | VCC = 3 V | | -24 | |
| | | $V_{CC} = 4.5 V$ | | -24 | |
| | | V _{CC} = 1.65 V | | 4 | |
| | | $V_{CC} = 2.3 V$ | | 8 | |
| I _{OL} | Low-level output current | $V_{CC} = 3 V$ | | 16 | mA |
| | | $v_{CC} = 3 v$ | | 24 | |
| | | $V_{CC} = 4.5 V$ | | 24 | |
| | | V_{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V | | 20 | |
| Δt/Δv | Input transition rise or fall rate | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | | 10 | ns/V |
| | | $V_{CC} = 5 V \pm 0.5 V$ | | 5 | |
| T _A | Operating free-air temperature | | -40 | 125 | °C |

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | V _{cc} | MIN TYP ⁽¹⁾ MAX | UNIT | | | |
|-------------------|--|-----------------|----------------------------|------|--|--|--|
| | $I_{OH} = -100 \ \mu A$ | 1.65 V to 5.5 V | V _{CC} – 0.1 | | | | |
| | $I_{OH} = -4 \text{ mA}$ | 1.65 V | 1.2 | | | | |
| M | $I_{OH} = -8 \text{ mA}$ | 2.3 V | 1.9 | V | | | |
| V _{OH} | $I_{OH} = -16 \text{ mA}$ | 3 V | 2.4 | V | | | |
| | | 3 V | 2.3 | | | | |
| | $I_{OH} = -24 \text{ mA}$ | 4.5 V | 3.8 | | | | |
| | I _{OL} = 100 μA | 1.65 V to 5.5 V | 0.1 | | | | |
| | I _{OL} = 4 mA | 1.65 V | 0.45 | | | | |
| N/ | I _{OL} = 8 mA | 2.3 V | 0.3 | V | | | |
| V _{OL} | I _{OL} = 16 mA | 3 V | 0.4 | | | | |
| | | 3 V | 0.55 | | | | |
| | I _{OL} = 24 mA | 4.5 V | 0.55 | | | | |
| II A or OE inputs | $V_1 = 5.5 \text{ V or GND}$ | 0 to 5.5 V | ±5 | μΑ | | | |
| l _{off} | V_{I} or $V_{O} = 5.5 V$ | 0 | ±10 | μΑ | | | |
| I _{OZ} | $V_0 = 0$ to 5.5 V | 3.6 V | 10 | μΑ | | | |
| I _{CC} | $V_{I} = 5.5 \text{ V or GND}, \qquad I_{O} = 0$ | 1.65 V to 5.5 V | 10 | μΑ | | | |
| ΔI _{CC} | One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND | 3 V to 5.5 V | 500 | μΑ | | | |
| C _i | $V_{I} = V_{CC}$ or GND | 3.3 V | 4 | pF | | | |

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25 ^{\circ}C.

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CC} = ± 0.3 | 3.3 V 3 V | V _{CC} = ± 0.5 | 5 V 5 V | UNIT |
|------------------|-----------------|----------------|----------------------------|--------------|----------------------------|------------|------|
| | (INFOT) | (001201) | MIN | MAX | MIN | MAX | |
| t _{pd} | A | Y | 1 | 5.8 | 1 | 4.5 | ns |
| t _{en} | OE | Y | 1.2 | 5.8 | 1 | 5 | ns |
| t _{dis} | OE | Y | 1 | 6 | 1 | 4.2 | ns |

Operating Characteristics

 $T_A = 25^{\circ}C$

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| | PARAMETER | TEST CONDITIONS | V _{CC} = 3.3 V TYP | V _{CC} = 5 V TYP | UNIT | |
|-----------------|-------------------------------|--------------------|--------------------------------|------------------------------|------|----|
| 0 | Dower dissinction consultance | Outputs enabled | f = 10 MHz | 19 | 21 | рF |
| C _{pd} | Power dissipation capacitance | Outputs disabled | | 3 | 4 | рг |

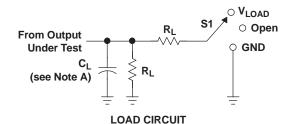
SN74LVC1G126-Q1

ÈXAS **INSTRUMENTS**

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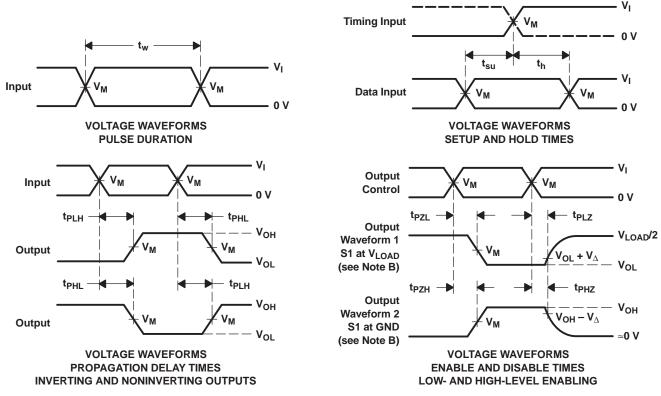
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PARAMETER MEASUREMENT INFORMATION



| TEST | S1 |
|------------------------------------|-------|
| t _{PLH} /t _{PHL} | Open |
| t _{PLZ} /t _{PZL} | VLOAD |
| t _{PHZ} /t _{PZH} | GND |

| V | | INF | PUTS | V | N/ | • | | N |
|-----------------|-----|-----|--------------------------------|--------------------|---------------------------|-------|--------------|----------------|
| V _{CC} | , | VI | t _r /t _f | V _M | V _{LOAD} | CL | RL | V _Δ |
| 3.3 V ± 0.3 | V 3 | 3 V | ≤ 2.5 ns | 1.5 V | 6 V | 50 pF | 500 Ω | 0.3 V |
| $5 V \pm 0.5$ | v v | /cc | ≤ 2.5 ns | V _{CC} /2 | $2\times \mathbf{V_{CC}}$ | 50 pF | 500 Ω | 0.3 V |



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



11-Apr-2013

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package | Pins | Package | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Top-Side Markings | Samples |
|------------------|--------|--------------|---------|------|---------|----------------------------|------------------|--------------------|--------------|-------------------|---------|
| | (1) | | Drawing | | Qty | (2) | | (3) | | (4) | |
| 1P1G126QDBVRQ1 | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C26O | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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OTHER QUALIFIED VERSIONS OF SN74LVC1G126-Q1 :

• Catalog: SN74LVC1G126



PACKAGE OPTION ADDENDUM

11-Apr-2013

Enhanced Product: SN74LVC1G126-EP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions are nominal | |
|-----------------------------|--|
|-----------------------------|--|

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| 1P1G126QDBVRQ1 | SOT-23 | DBV | 5 | 3000 | 179.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

14-Mar-2013



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| 1P1G126QDBVRQ1 | SOT-23 | DBV | 5 | 3000 | 203.0 | 203.0 | 35.0 |

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- All linear dimensions are in millimeters. A.
 - This drawing is subject to change without notice. Β.
 - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side. C.
 - D. Falls within JEDEC MO-178 Variation AA.



DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.

- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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